US2AA ~ US2MA

RECTIFIER DIODE

-2A IF, -50V~1000V REVERSE VOLTAGE, ULTRAFAST RECOVERY RECTIFIER

DESCRIPTION

The US2AA ~ US2MA is available in SMA package.

FEATURE

- For Surface Mounted Applications
- Low Profile Package
- Glass Passivated Chip Junction
- High Efficiency

MECHANICAL DATA

- Case: SMA
- Terminals: Solderable per MIL-STD-750, Method
 2026
- Approx. Weight: 0.055g / 0.002oz

PIN DESCRIPTION



ORDERING INFORMATION

Package Type	Part Number			
	US2AA			
SMA	US2BA			
	US2DA			
	US2GA			
	US2JA			
	US2KA			
	US2MA			
Note	SPQ: 5,000pcs/Reel			
AiT provides all RoHS Compliant Products				



PIN#	DESCRIPTION	
1	CATHODE	
2	ANODE	

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MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase half- -wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Paramete	_	Symbol	US2AA	US2BA	US2DA	US2GA	US2JA	US2KA	US2MA	Unit
Maximum Repetitive Peak		V	50	100	200	400	600	800	1000	V
Reverse Voltage		V_{RRM}	50	100	200	400	000	800	1000	V
Maximum RMS Volta	age	V_{RWS}	35	70	140	280	420	560	700	V
Maximum DC Blocki	ng Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward		_	2							А
Rectified Current at T _a =65°C		I _{F(AV)}								
Peak Forward Surge	Peak Forward Surge Current		70							А
8.3ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)		I _{FSM}								
			Maximum Instantaneous Forward Voltage at 2A		V _F	1	1	1	1.30	
'										
Maximum DC	T _a =25°C		5							
Reverse Current at	1 _a -23 C	l _R								
Rated DC Blocking	T _a =125°C	^I R	100							μΑ
Voltage	1 _a -125 C									
Maximum Reverse R	ecovery		50	50	50	50	75	75	75	ns
Time		t _{rr}	30	30	30	30	13	13	13	113
Typical Junction Cap	acitance	C_T	т 65			рF				
Typical Thermal Capa	acitance	$R_{\theta JA}$	20		20	20			°C/W	
Operating Temperat	ture Range	TJ	-55 ~ + 150			°C				
Storage Temperatur	e Range	T _{STG}	-55 ~ + 150				°C			

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TYPICAL PERFORMANCE CHARACTERISTICS

Fig 1. Forward Current Derating Curve

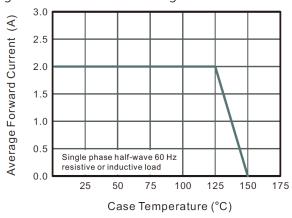


Fig 2. Typical Reverse Characteristics

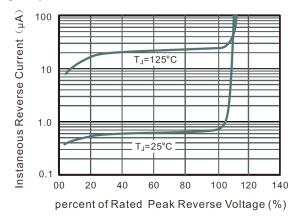


Fig 3. Typical Forward Characteristics

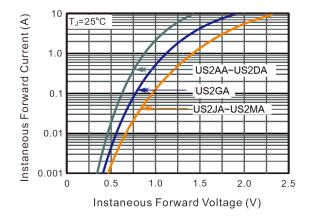
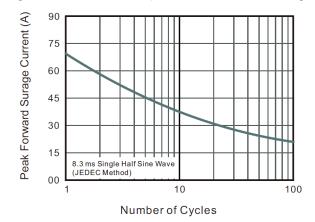


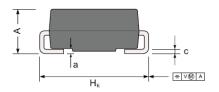
Fig 4. Maximum Non-Repetitive Peak Forward Surge Current

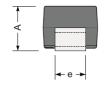


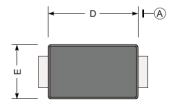
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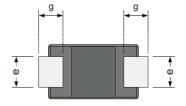
PACKAGE INFORMATION

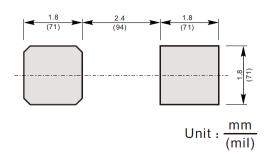
Dimension in SMA Package











The Recommended Mounting Pad Size

DIM	MILLIMETERS				
DIM	MIN	MAX			
А	1.900	2.200			
а	0.300 TYP.				
С	0.150	0.310			
D	4.000	4.500			
E	2.300	2.700			
е	1.300	1.600			
g	0.900	1.500			
H _E	4.700	5.200			

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